

Dependence of the Electrical Conductivity and Thermoelectric Coefficient of Aluminum-Doped Rutile on Equilibrium Oxygen Pressure

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#	ARTICLE	IF	CITATIONS
1	The temperature variation of electronic mobility in rutile (TiO ₂) and $\hat{I}\pm$ -Nb ₂ O ₅ at elevated temperatures. Journal of Physics and Chemistry of Solids, 1964, 25, 881-887.	4.0	11
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